

- Flow-Through Architecture Optimizes PCB Layout
- Center-Pin V_{CC} and GND Configurations Minimize High-Speed Switching Noise
- EPIC™ (Enhanced-Performance Implanted CMOS) 1-μm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

description

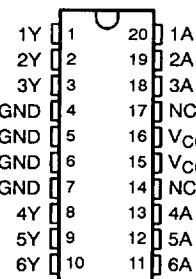
These devices contain six independent inverters. They perform the Boolean functions $Y = \bar{A}$.

The 54AC11004 is characterized for operation over the full military temperature range of -55°C to 125°C. The 74AC11004 is characterized for operation from -40°C to 85°C.

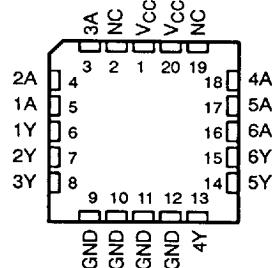
FUNCTION TABLE
(each Inverter)

INPUT A	OUTPUT Y
H	L
L	H

54AC11004 . . . J PACKAGE
74AC11004 . . . DW OR N PACKAGE
(TOP VIEW)

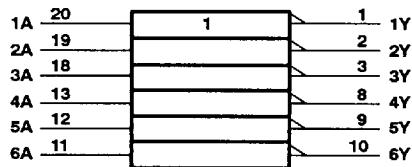


54AC11004 . . . FK PACKAGE
(TOP VIEW)



NC - No internal connection

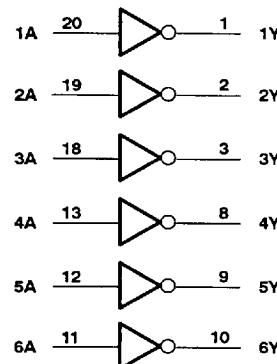
logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the DW, J, and N packages.

logic diagram (positive logic)



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PRODUCTION DATA information is current as of publication date.
Products conform to specifications per the terms of Texas Instruments
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testing of all parameters.

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54AC11004, 74AC11004 HEX INVERTERS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC}	-0.5 V to 7 V
Input voltage range, V _I (see Note 1)	-0.5 V to V _{CC} + 0.5 V
Output voltage range, V _O (see Note 1)	-0.5 V to V _{CC} + 0.5 V
Input clamp current, I _{IK} (V _I < 0 or V _I > V _{CC})	±20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±50 mA
Continuous output current, I _O (V _O = 0 to V _{CC})	±50 mA
Continuous current through V _{CC} or GND	±100 mA
Storage temperature range	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

recommended operating conditions

		54AC11004			74AC11004			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC}	Supply voltage	3	5	5.5	3	5	5.5	V
VIH	High-level input voltage	V _{CC} = 3 V	2.1		2.1			V
		V _{CC} = 4.5 V	3.15		3.15			
		V _{CC} = 5.5 V	3.85		3.85			
VIL	Low-level input voltage	V _{CC} = 3 V		0.9		0.9		V
		V _{CC} = 4.5 V		1.35		1.35		
		V _{CC} = 5.5 V		1.65		1.65		
V _I	Input voltage	0	V _{CC}		0	V _{CC}		V
V _O	Output voltage	0	V _{CC}		0	V _{CC}		V
I _{OH}	High-level output current	V _{CC} = 3 V		-4		-4		mA
		V _{CC} = 4.5 V		-24		-24		
		V _{CC} = 5.5 V		-24		-24		
I _{OL}	Low-level output current	V _{CC} = 3 V		12		12		mA
		V _{CC} = 4.5 V		24		24		
		V _{CC} = 5.5 V		24		24		
Δt/Δv	Input transition rise or fall rate	0	10		0	10		ns/V
T _A	Operating free-air temperature	-55	125		-40	85		°C

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	T _A = 25°C			54AC11004	74AC11004	UNIT
			MIN	TYP	MAX	MIN	MAX	
V _{OH}	I _{OH} = -50 µA	3 V	2.9			2.9	2.9	V
		4.5 V	4.4			4.4	4.4	
		5.5 V	5.4			5.4	5.4	
	I _{OH} = -4 mA	3 V	2.58			2.4	2.48	
		4.5 V	3.94			3.7	3.8	
	I _{OH} = -24 mA	5.5 V	4.94			4.7	4.8	
V _{OL}	I _{OH} = -50 mA [†]	5.5 V				3.85		V
	I _{OH} = -75 mA [†]	5.5 V					3.85	
	I _{OL} = 50 µA	3 V		0.1		0.1	0.1	
		4.5 V		0.1		0.1	0.1	
		5.5 V		0.1		0.1	0.1	
	I _{OL} = 12 mA	3 V		0.36		0.5	0.44	
	I _{OL} = 24 mA	4.5 V		0.36		0.5	0.44	
		5.5 V		0.36		0.5	0.44	
I _I	I _{OL} = 50 mA [†]	5.5 V				1.65		µA
	I _{OL} = 75 mA [†]	5.5 V					1.65	
	I _I , V _I = V _{CC} or GND	5.5 V		±0.1		±1	±1	
	I _{CC} , V _I = V _{CC} or GND, I _O = 0	5.5 V		4		80	40	
	C _I , V _I = V _{CC} or GND	5 V		3.5				
								pF

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

switching characteristics over recommended operating free-air temperature range,
V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	T _A = 25°C			54AC11004	74AC11004	UNIT	
			MIN	TYP	MAX	MIN	MAX		
t _{PLH}	A	Y	1.5	6.1	9	1.5	10.4	1.5	ns
			1.5	5.2	7.4	1.5	8.9	1.5	

switching characteristics over recommended operating free-air temperature range,
V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	T _A = 25°C			54AC11004	74AC11004	UNIT	
			MIN	TYP	MAX	MIN	MAX		
t _{PLH}	A	Y	1.5	4.2	6.3	1.5	7.5	1.5	ns
			1.5	3.8	5.5	1.5	6.4	1.5	

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER	TEST CONDITIONS	TYP	UNIT	
C _{pd}	Power dissipation capacitance per gate	C _L = 50 pF, f = 1 MHz	29	pF



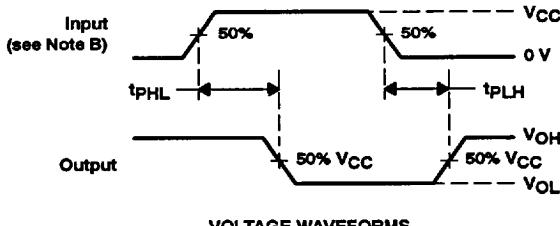
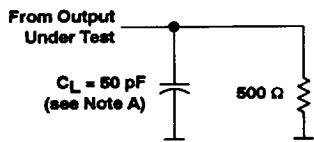
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PARAMETER MEASUREMENT INFORMATION



LOAD CIRCUIT

VOLTAGE WAVEFORMS

- NOTES: A. C_L includes probe and jig capacitance.
B. Input pulses are supplied by generators having the following characteristics: PRR $\leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r = 3 \text{ ns}$, $t_f = 3 \text{ ns}$.
C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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